

NCE40TD120BT

1200V, 40A, Trench FS II Fast IGBT

General Description:

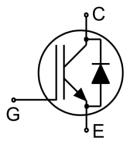
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low V_{CE(sat)}
- High speed switching
- Positive temperature coefficient in V_{CE(sat)}
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Inverters
- Motor drives
- Converter



Schematic diagram

Package Marking and Ordering Information

Device	Device Package	Device Marking
NCE40TD120BT	TO-247	NCE40TD120BT



TO-247

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
Vces	Collector-Emitter Voltage	1200	V
V_{GES}	Gate- Emitter Voltage	±30	V
1-	Collector Current	80	Α
lc	Collector Current @T _C = 100 °C	40	А
I _{Cpuls}	Pulsed Collector Current, t _p limited by T _{jmax}	120	А
-	turn off safe operating area, V _{CE} =1200V, Tj=150°C	120	А
l _F	Diode Continuous Forward Current @Tc = 100 °C	40	А
Іғм	Diode Maximum Forward Current	120	А
Б	Power Dissipation @ T _C = 25°C	468	W
P _D	Power Dissipation @T _C = 100 °C	234	W
T _J ,T _{stg}	Operating Junction and Storage Temperature Range	-55 to +175	°C
TL	Maximum Temperature for Soldering	260	°C
t _{sc}	Short circuit withstand time V_{GE} =15.0V, V_{CC} <600V, Allowed number of short circuits<1000Time between short circuits: \ge 1.0s, T_j <150°C	10	us



Thermal Characteristic

Symbol	Parameter	Value	Units
Rejc	Thermal Resistance, Junction to case for IGBT	0.32	°C/W
Rejc	Thermal Resistance, Junction to case for Diode	0.61	°C/W
RθJA	Thermal Resistance, Junction to Ambient	40	°C/W

Electrical Characteristics (Tc=25°C unless otherwise noted)

Compleal	Barrantar	Test Conditions		Value			
Symbol	Parameter			Min.	Тур.	Max.	Units
Static Chara	cteristics						
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V	,I _{CE} =1mA	1200			V
Ices	Collector-Emitter Leakage Current	V _{GE} =0V,	/ _{CE} =1200V			5	uA
I _{GES(F)}	Gate to Emitter Forward Leakage	V _{GE} =+30	V,V _{CE} =0V			200	nA
I _{GES(R)}	Gate to Source Reverse Leakage	V _{GE} =-30	V,Vce =0V			200	nA
1/	Calleston Fraitton Caturation Valteur	Ic=40A	Tj=25°C		1.55	1.8	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$V_{\text{GE}}=15V$	Tj=150°C		1.8		V
$V_{GE(th)}$	Gate Threshold Voltage	Ic=1mA	,Vce=Vge	5.0		6.5	V
I _{C(SC)}	Short circuit collector current Max.1000 short circuits Time between short circuits: ≥1.0s	V _{GE} =15V,V _{CC} ≤600V, t _{SC} ≤10us,Tj≤150°C			240		Α
Dynamic Ch	aracteristics						
Cies	Input Capacitance	\/ 00\	/		5590		
Coes	Output Capacitance	Vce=30V,Vge=0V, f=1MHz			177		pF
Cres	Reverse Transfer Capacitance				134		
Qg	Total Gate Charge	Vcc=960V, Ic=40A, V _{GE} =15V			298		nC
Q _{ge}	Gate to Emitter Charge				52		
Q _{gc}	Gate to Collector Charge	VGL	-101		169		
Switching Cl	naracteristics						
t _{d(ON)}	Turn-on Delay Time				19		
t _r	Rise Time				17		20
t _{d(OFF)}	Turn-Off Delay Time	V_{CE} =600V, I_{C} =40A, V_{GE} =0/15V, R_{g} =8 Ω			170		ns
t f	Fall Time				18		
Eon	Turn-On Switching Loss	Inducti	ve Load		2.3		
E _{off}	Turn-Off Switching Loss				1.6		mJ
E _{ts}	Total Switching Loss				3.9		

Electrical Characteristics of the Diode(Tc= 25°C unless otherwise specified):

Symbol	Parameter	Test Conditions	Rating			Units
			Min.	Тур.	Max.	Ullits
V_{FM}	Diode Forward Voltage	I _F =40A		2.1	2.8	V
Trr	Reverse Recovery Time	I- 40A		180		ns
I _{RRM}	Diode Peak Reverse Recovery Current	Ir=40A, di/dt=500A/us		10		А
Qrr	Reverse Recovery Charge	ui/ui=300A/us		2.4		uC
Pulse width t _{tp} ≤380μs,δ≤2%						

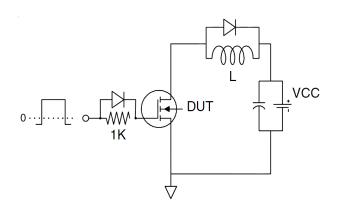


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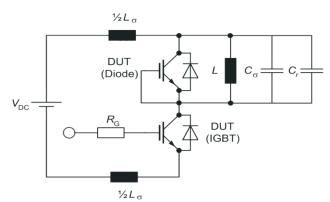
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Test Circuit

1) Gate Charge Test Circuit

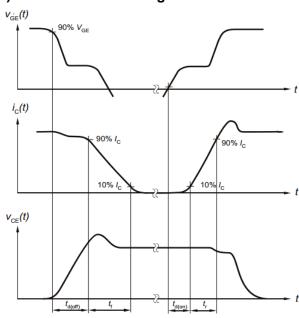


2) Switch Time Test Circuit

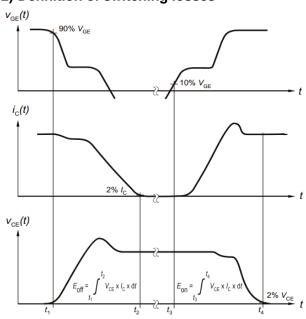


Switching characteristics

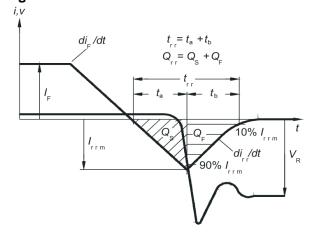
1) Definition of switching times



2) Definition of switching losses



3) Definition of diode switching characteristics





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Typical Electrical and Thermal Characteristics



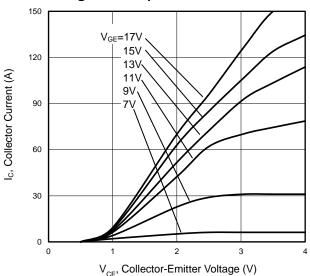


Figure 3 V_{CE(sat)} vs. Case Temperature

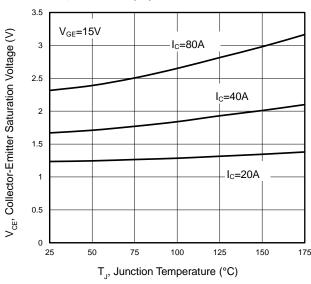


Figure 5 Capacitance Characteristics

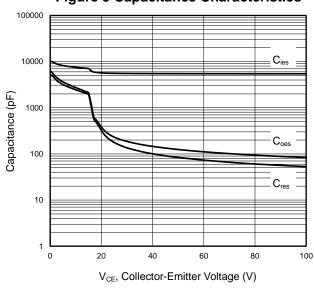


Figure 2 Transfer Characteristics

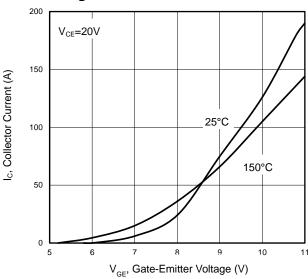


Figure 4 Saturation Voltage vs. V_{GE}

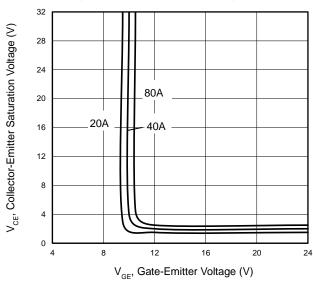
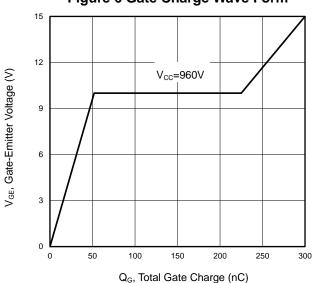
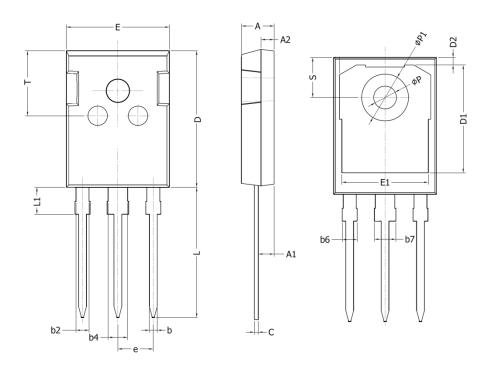


Figure 6 Gate Charge Wave Form





TO-247 Package Information



Combal	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.90	5.10	0.193	0.201	
A1	2.31	2.51	0.091	0.099	
A2	1.9	2.1	0.075	0.083	
b	1.16	1.26	0.046	0.050	
b2	1.96	2.06	0.077	0.081	
b4	2.96	3.06	0.117	0.120	
b6	-	2.25	-	0.089	
b7	-	3.25	-	0.128	
С	0.59	0.66	0.023	0.026	
D	20.90	21.10	0.823	0.831	
D1	16.25	16.85	0.640	0.663	
D2	1.05	1.35	0.041	0.053	
Е	15.70	15.90	0.618	0.626	
E1	13.10	13.50	0.516	0.531	
е	5.436	BSC	0.214 BSC		
L	19.80	20.10	0.780	0.791	
L1	-	4.30	-	0.169	
Р	3.40	3.60	0.134	0.142	
P1	7.00	7.40	0.276	0.291	
S	6.05	6.25	0.238	0.246	
Т	9.80	10.20	0.386	0.402	

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